

BC857B-QVL Datasheet



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DiGi Electronics Part Number BC857B-QVL-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC857B-QVL

Description TRANS PNP 45V 0.1A TO236AB

Detailed Description Bipolar (BJT) Transistor PNP 45 V 100 mA 100MHz 2

50 mW Surface Mount TO-236AB



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC857B-QVL	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	220 @ 2mA, 5V
Power - Max:	Frequency - Transition:
250 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
BC857	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



65 V, 100 mA PNP general-purpose transistors

Rev. 2 — 21 February 2022

Product data sheet

1. General description

PNP general-purpose transistors in a small SOT23 (TO-236AB), Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	NPN complement	
	Nexperia	JEDEC	
BC856-Q	SOT23	TO-236AB	BC846-Q
BC856A-Q			BC846A-Q
BC856B-Q			BC846B-Q
BC857-Q			BC847-Q
BC857A-Q			BC847A-Q
BC857B-Q			BC847B-Q
BC857C-Q			BC847C-Q
BC858B-Q			BC848B-Q

2. Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 65 V)
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

General-purpose switching and amplification



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4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		_		
	BC856-Q; BC856A-Q; BC856B-Q		-	-	-65	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q		-	-	-45	V
	BC858B-Q		-	-	-30	V
I _C	collector current		-	-	-100	mA
I _{CM}	peak collector current		-	-	-200	mA
h _{FE}	DC current gain					
	BC856-Q		125	-	475	
	BC857-Q		125	-	800	
	BC856A-Q; BC857A-Q	V _{CE} = 5 V; I _C = 2 mA	125	-	250	
	BC856B-Q; BC857B-Q; BC858B-Q	VCE - 3 V, IC - 2 IIIA	220	-	475	
	BC857C-Q		420	-	800	

5. Pinning information

Table 3. Pinning information

Pin	Symbol	Descrition	Simlified outline	Graphic symbol
1	В	base]3	C
2	E	emitter		R—
3	С	collector		, h
				E122
			1 2	sym132

6. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
BC856-Q	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			
BC856A-Q						
BC856B-Q						
BC857-Q						
BC857A-Q						
BC857B-Q						
BC857C-Q						
BC858B-Q						

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7. Marking

Table 5. Marking codes

Type number		Marking code
BC856-Q	[1]	3D%
BC856A-Q	[1]	3A%
BC856B-Q	[1]	3B%
BC857-Q	[1]	3H%
BC857A-Q	[1]	3E%
BC857B-Q	[1]	3F%
BC857C-Q	[1]	3G%
BC858B-Q	[1]	3K%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter				
	BC856-Q; BC856A-Q; BC856B-Q			-	-80	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q			-	-50	V
	BC858B-Q			-	-30	V
V _{CEO}	collector-emitter voltage	open base				
	BC856-Q; BC856A-Q; BC856B-Q			-	-65	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q			-	-45	V
	BC858B-Q			-	-30	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current			-	-200	mA
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
· -ui(y-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB; single-sided, 35 µm copper; tin-plated and standard footprint.

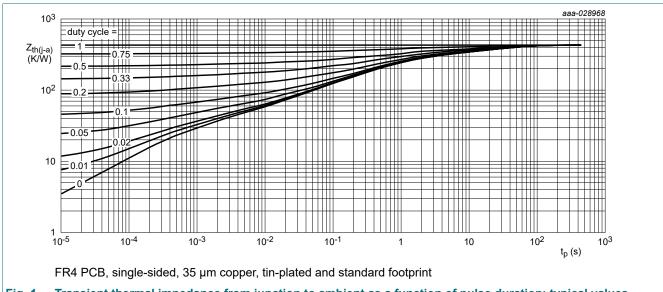


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

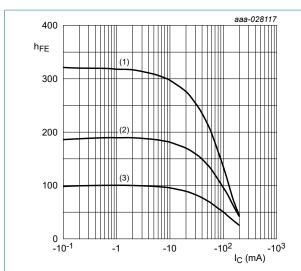
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdow	vn voltage					
	BC856-Q; BC856A-Q; BC856B-Q			-80	-	-	V
BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q		I _C = -100 μA; I _E = 0 A		-50	-	-	V
	BC858B-Q			-30	-	-	V
V _{(BR)CEO}	collector-emitter breakdo	own voltage					
	BC856-Q; BC856A-Q; BC856B-Q			-65	-	-	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q	$I_{C} = -2 \text{ mA}; I_{B} = 0 \text{ A}$		-45	-	-	V
BC858B-Q	BC858B-Q			-30	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _C = 0 A; I _E = -100 μA		-5	-	-	V
I _{CBO} collector-base cut-off current		V _{CB} = -30 V; I _E = 0 A		-	-1	-15	nA
		V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-4	μA
ЕВО	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain						
	BC856-Q			125	-	475	
	BC857-Q			125	-	800	
	BC856A-Q; BC857A-Q	$V_{CF} = -5 \text{ V; } I_{C} = -2 \text{ mA}$		125	-	250	
	BC856B-Q; BC857B-Q; BC858B-Q	VCE0 V, IC2 IIIA		220	-	475	
	BC857C-Q			420	-	800	
V _{CEsat}	collector-emitter	I _C = -10 mA; I _B = -0.5 mA		-	-75	-300	mV
	saturation voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-250	-650	mV
V _{BEsat}	base-emitter saturation	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	[1]	-	-700	-	mV
	voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-850	-	mV
V _{BE}	base-emitter voltage	V _{CE} = -5 V; I _C = -2 mA		-600	-650	-750	mV
		V _{CE} = -5 V; I _C = -10 mA		-	-	-820	mV
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	4.5	-	pF
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz		100	-	-	MHz
NF	noise figure	I_C = -200 μA; V_{CE} = -5 V; R_S = 2 kΩ; f = 1 kHz; B = 200Hz		-	2	10	dB

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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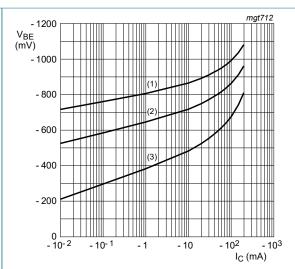
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 2. BC856A-Q; BC857A-Q: DC current gain as a function of collector current; typical values



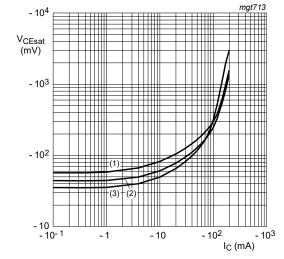
$$V_{CE}$$
 = -5 V

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 3. BC856A-Q; BC857A-Q: Base-emitter voltage as a function of collector current; typical values

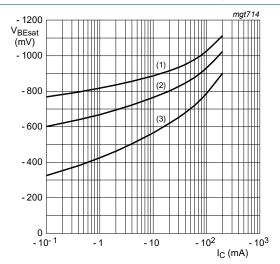


$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 150 °C$$

$$(3) T_{amb} = -55 °C$$

Fig. 4. BC856A-Q; BC857A-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

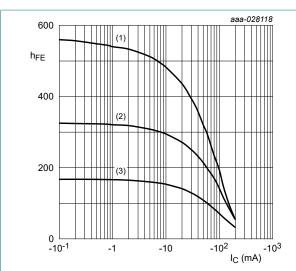
(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC856A-Q; BC857A-Q: Base-emitter saturation voltage as a function of collector current; typical values

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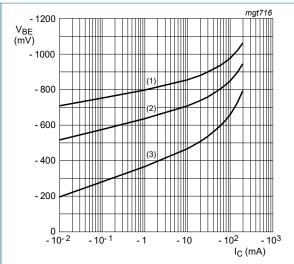
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 6. BC856B-Q; BC857B-Q; BC858B-Q: DC current gain as a function of collector current; typical values



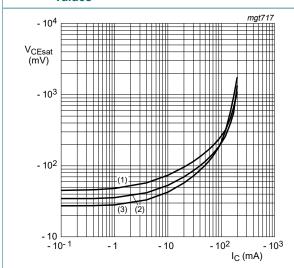
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. BC856B-Q; BC857B-Q; BC858B-Q: Base-emitter voltage as a function of collector current; typical values



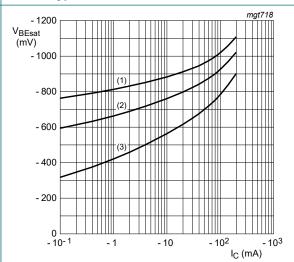
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC856B-Q; BC857B-Q; BC858B-Q: Collectoremitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

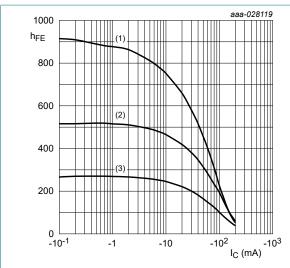
(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC856B-Q; BC857B-Q; BC858B-Q: Base-emitter saturation voltage as a function of collector current; typical values

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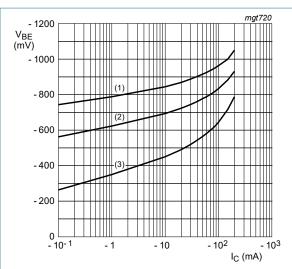
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC857C-Q: DC current gain as a function of collector current; typical values



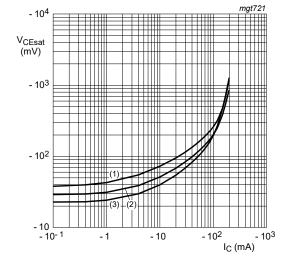
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 11. BC857C-Q: Base-emitter voltage as a function of collector current; typical values



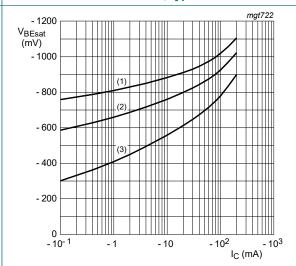
$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 150 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC857C-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb}$$
 = 150 °C

Fig. 13. BC857C-Q: Base-emitter saturation voltage as a function of collector current; typical values

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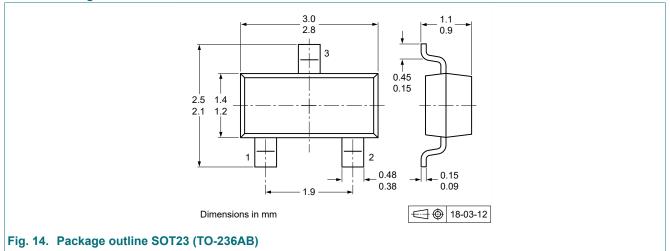
11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline

Table 9. Package outline

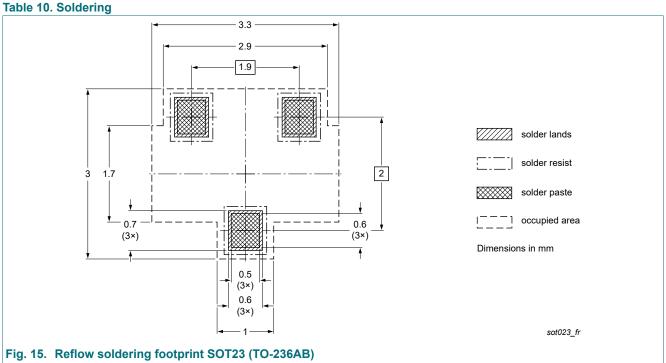


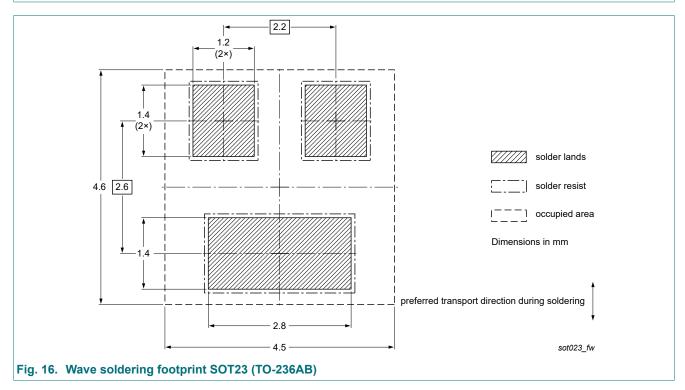
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13. Soldering







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14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BC856-Q_BC857-Q_BC858-Q v.2	20220221	Product data sheet	-	BC856-Q_BC857-Q_BC858-Q v.1		
Modifications:	 Quick reference data: BC856-Q corrected to BC856B-Q at h_{FE} Limiting values and Characteristics: Product names changed to detailed descriptions 					
BC856-Q_BC857-Q_BC858-Q v.1	20210624	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Nexperia

BC856-Q; BC857-Q; BC858-Q

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